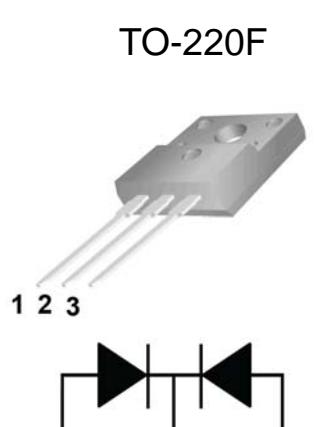


MURF1010CT – MURF1060CT Features: <ul style="list-style-type: none"> <input type="checkbox"/> High surge capacity <input type="checkbox"/> Low Forward Voltage Drop. <input type="checkbox"/> High Current Capability. <input type="checkbox"/> Super Fast Switching Speed For High Efficiency 	 TO-220F  1. Anode 2. Cathode 3. Anode
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Absolute Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	MUR F1010 CT	MUR F1015 CT	MUR F1020 CT	MUR F1040 CT	MUR F1060 CT	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	100	150	200	400	600	V
Working Peak Reverse Voltage	V_{RWM}	70	105	140	280	420	V
DC Blocking Voltage	$V_{R(DC)}$	100	150	200	400	600	V
Average Rectified Forward Current Per Leg Total Device, (Rated V_R), Total Device	$I_{F(AV)}$			5 10			A
Peak Rectified Forward Current Per Diode Leg (Rated V_R , Square Wave, 20 kHz),	I_{FM}			10			A
Nonrepetitive Peak Surge Current(Surge applied at rated load conditions half wave, single phase, 60 Hz)	I_{FSM}			150			A
Operating Junction Temperature and Storage Temperature	T_J, T_{Stg}			-55 to +150			$^\circ\text{C}$
Maximum Thermal Resistance, Junction-to-Case(Per Leg)	$R_{\theta JC}$			2.0			$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	MUR F1010 CT	MUR F1015 CT	MUR F1020 CT	MUR F1040 CT	MUR F1060 CT	Unit
Forward Voltage (Note 1) ($I_F = 5\text{ A}$, $T_C = 25^\circ\text{C}$)	V_F	0.975		1.3	1.70		V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 125^\circ\text{C}$)	I_R		10 500				μA
Maximum Reverse Recovery Time ($I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{REC} = 0.25\text{ A}$)	T_{RR}		35				ns

 Note 1.Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

Typical Characteristics

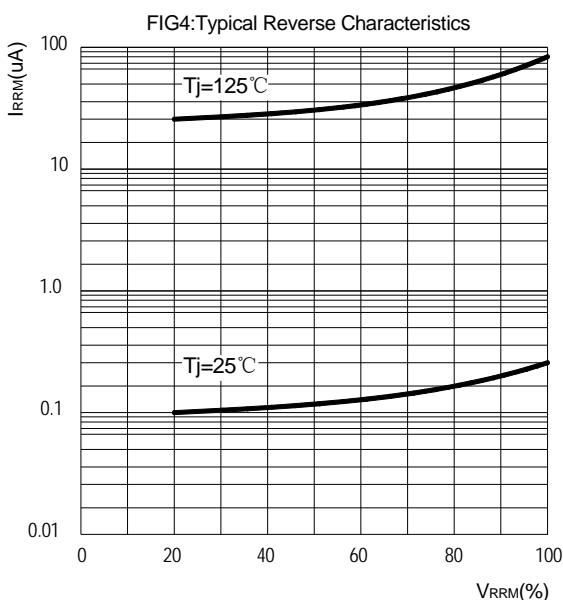
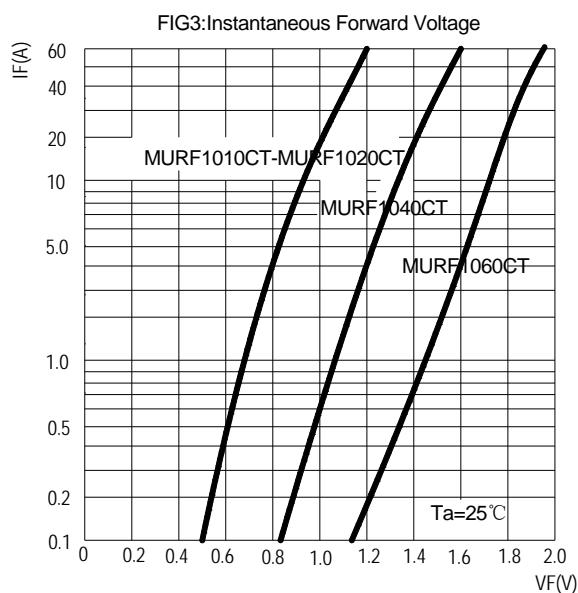
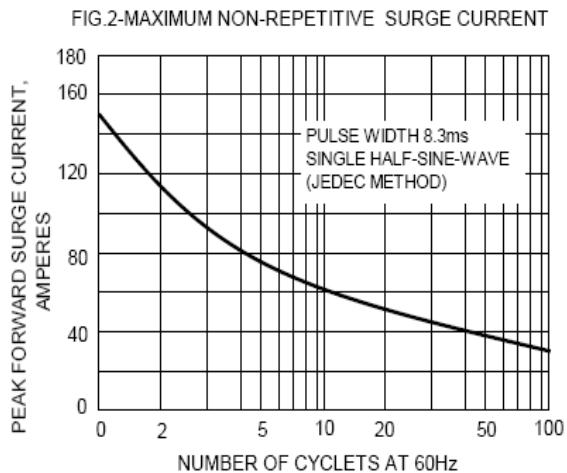
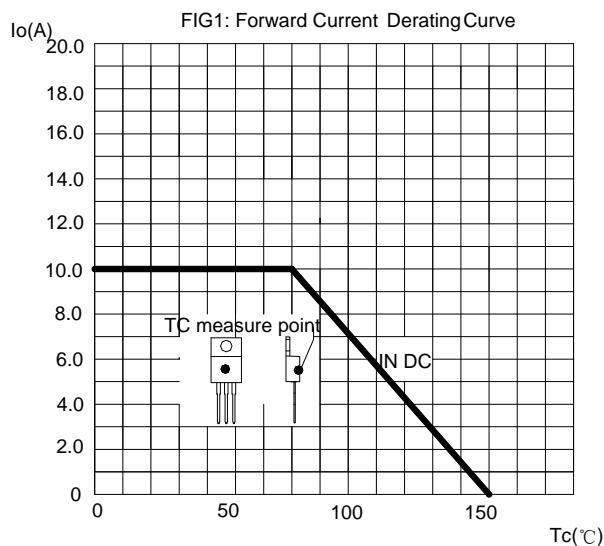
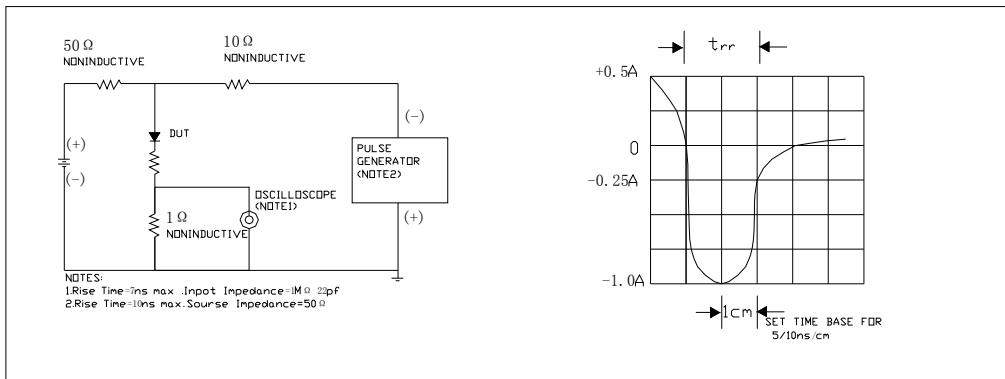


Diagram of circuit and Testing wave form of reverse recovery time



Package Dimension

TO-220F

Unit: mm

